NSN 5961-00-904-8133

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Inclosure Material:	Incl	osure	Mater	ial:
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Metal

Overall Length:

0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, collector-to-base, emitter open and 200.0 breakdown voltage, collector-to-emitter, base open and 10.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 250.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release4159a professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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